

# Programmable Unijunction Transistors

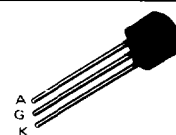
## Silicon Programmable Unijunction Transistors

... designed to enable the engineer to "program" unijunction characteristics such as  $R_{BB}$ ,  $\eta$ ,  $I_V$ , and  $I_P$  by merely selecting two resistor values. Application includes thyristor-trigger, oscillator, pulse and timing circuits. These devices may also be used in special thyristor applications due to the availability of an anode gate. Supplied in an inexpensive TO-92 plastic package for high-volume requirements, this package is readily adaptable for use in automatic insertion equipment.

- Programmable —  $R_{BB}$ ,  $\eta$ ,  $I_V$  and  $I_P$ .
- Low On-State Voltage — 1.5 Volts Maximum @  $I_F = 50$  mA
- Low Gate to Anode Leakage Current — 10 nA Maximum
- High Peak Output Voltage — 11 Volts Typical
- Low Offset Voltage — 0.35 Volt Typical ( $R_G = 10$  k ohms)

**2N6027**  
**2N6028**

PUTs  
40 VOLTS  
300 mW



CASE 29-04  
(TO-226AA)  
STYLE 16

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### MAXIMUM RATINGS ( $T_J = 25^\circ\text{C}$ unless otherwise noted.)

Rating	Symbol	Value	Unit
*Power Dissipation Derate Above $25^\circ\text{C}$	$P_F$ $1/\theta_{JA}$	300 4	mW mW/ $^\circ\text{C}$
*DC Forward Anode Current Derate Above $25^\circ\text{C}$	$I_T$	150 2.67	mA mA/ $^\circ\text{C}$
*DC Gate Current	$I_G$	$\pm 50$	mA
Repetitive Peak Forward Current 100 $\mu\text{s}$ Pulse Width, 1% Duty Cycle *20 $\mu\text{s}$ Pulse Width, 1% Duty Cycle	$I_{TRM}$	1 2	Amps
Non-Repetitive Peak Forward Current 10 $\mu\text{s}$ Pulse Width	$I_{TSM}$	5	Amps
*Gate to Cathode Forward Voltage	$V_{GKF}$	40	Volts
*Gate to Cathode Reverse Voltage	$V_{GKR}$	-5	Volts
*Gate to Anode Reverse Voltage	$V_{GAR}$	40	Volts
*Anode to Cathode Voltage, Note 1	$V_{AK}$	$\pm 40$	Volts
Operating Junction Temperature Range	$T_J$	-50 to +100	$^\circ\text{C}$
*Storage Temperature Range	$T_{stg}$	-55 to +150	$^\circ\text{C}$

\*Indicates JEDEC Registered Data

Note 1. Anode positive,  $R_{GA} = 1000$  ohms  
Anode negative,  $R_{GA} = \text{open}$

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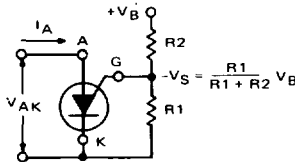
ELECTRICAL CHARACTERISTICS (T<sub>A</sub> = 25°C unless otherwise noted.)

Characteristic	Fig. No.	Symbol	Min	Typ	Max	Unit
*Peak Current (V <sub>S</sub> = 10 Vdc, R <sub>G</sub> = 1 MΩ)	2,9,11	I <sub>p</sub>	—	1.25	2	μA
(V <sub>S</sub> = 10 Vdc, R <sub>G</sub> = 10 k ohms)			—	0.08	0.15	
			—	4	5	
			—	0.70	1	
*Offset Voltage (V <sub>S</sub> = 10 Vdc, R <sub>G</sub> = 1 MΩ)	1	V <sub>T</sub>	0.2	0.70	1.6	Volts
(V <sub>S</sub> = 10 Vdc, R <sub>G</sub> = 10 k ohms)			0.2	0.50	0.6	
			0.2	0.35	0.6	
*Valley Current (V <sub>S</sub> = 10 Vdc, R <sub>G</sub> = 1 MΩ)	1,4,5	I <sub>v</sub>	—	18	50	μA
(V <sub>S</sub> = 10 Vdc, R <sub>G</sub> = 10 k ohms)			—	18	25	
			70	150	—	
			25	150	—	
(V <sub>S</sub> = 10 Vdc, R <sub>G</sub> = 200 ohms)			1.5	—	—	mA
			1	—	—	
*Gate to Anode Leakage Current (V <sub>S</sub> = 40 Vdc, T <sub>A</sub> = 25°C, Cathode Open)	—	I <sub>GAO</sub>	—	1	10	nAdc
(V <sub>S</sub> = 40 Vdc, T <sub>A</sub> = 75°C, Cathode Open)			—	3	—	
Gate to Cathode Leakage Current (V <sub>S</sub> = 40 Vdc, Anode to Cathode Shorted)	—	I <sub>GKS</sub>	—	5	50	nAdc
*Forward Voltage (I <sub>F</sub> = 50 mA Peak)	1,6	V <sub>F</sub>	—	0.8	1.5	Volts
*Peak Output Voltage (V <sub>G</sub> = 20 Vdc, C <sub>C</sub> = 0.2 μF)	3,7	V <sub>O</sub>	6	11	—	Volt
Pulse Voltage Rise Time (V <sub>B</sub> = 20 Vdc, C <sub>C</sub> = 0.2 μF)	3	t <sub>r</sub>	—	40	80	ns

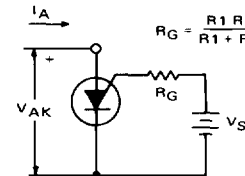
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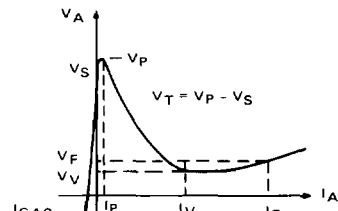
FIGURE 1 – ELECTRICAL CHARACTERIZATION



1A – Programmable Unijunction with "Program" Resistors R1 and R2



1B – Equivalent Test Circuit for Figure 1A used for electrical characteristics testing (also see Figure 2)



1C – Electrical Characteristics

FIGURE 2 – PEAK CURRENT (I<sub>p</sub>) TEST CIRCUIT

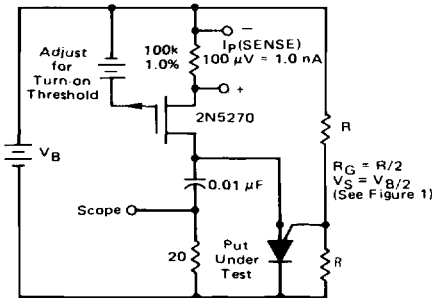
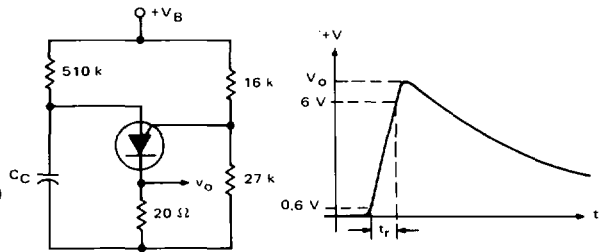


FIGURE 3 – V<sub>O</sub> AND t<sub>r</sub> TEST CIRCUIT



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### TYPICAL VALLEY CURRENT BEHAVIOR

FIGURE 4 – EFFECT OF SUPPLY VOLTAGE

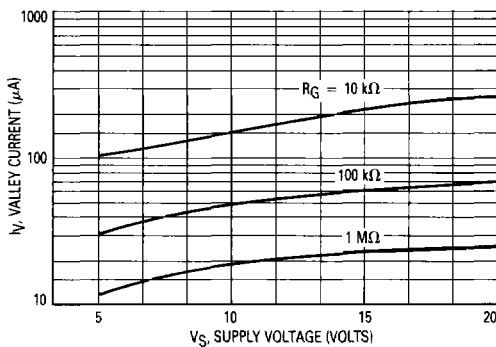


FIGURE 5 – EFFECT OF TEMPERATURE

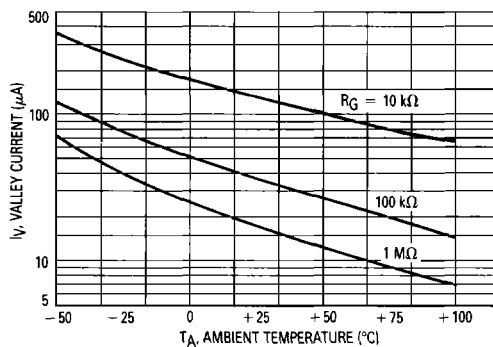


FIGURE 6 – FORWARD VOLTAGE

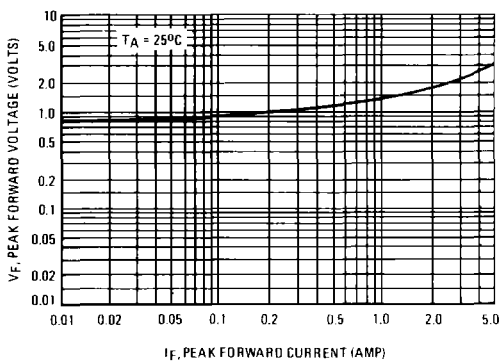


FIGURE 7 – PEAK OUTPUT VOLTAGE

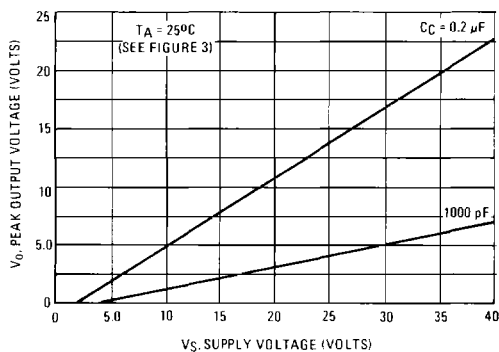
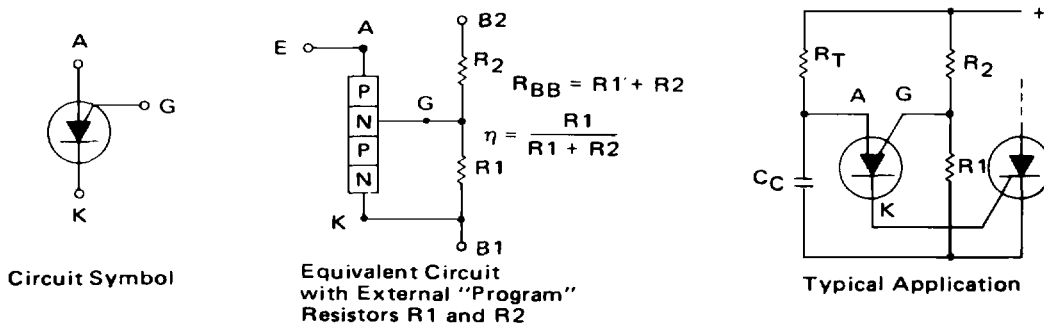


FIGURE 8  
PROGRAMMABLE UNIUNION



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TYPICAL PEAK CURRENT BEHAVIOR

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FIGURE 9 – EFFECT OF SUPPLY VOLTAGE AND  $R_G$

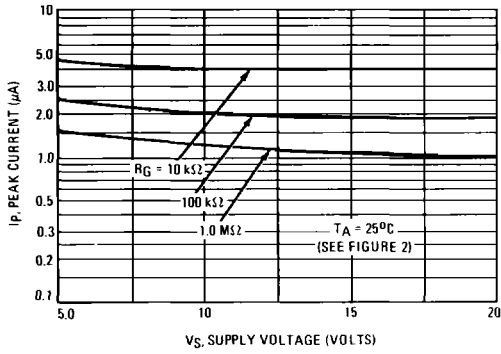
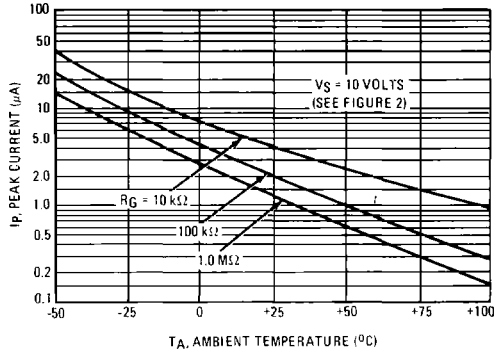


FIGURE 10 – EFFECT OF TEMPERATURE AND  $R_G$



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FIGURE 11 – EFFECT OF SUPPLY VOLTAGE AND  $R_G$

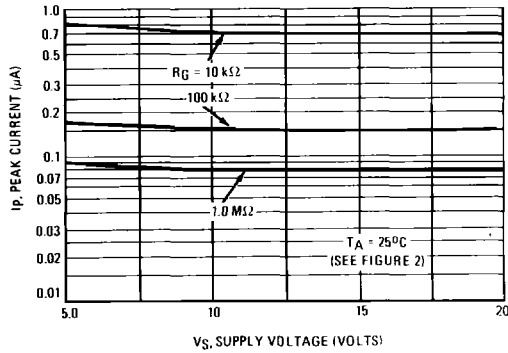
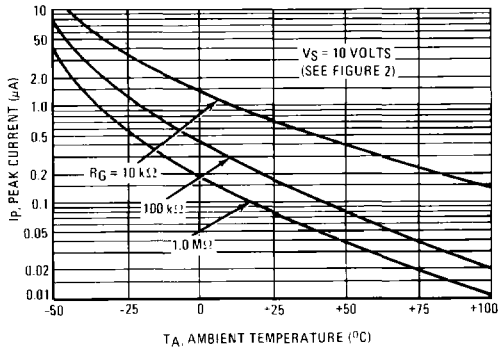


FIGURE 12 – EFFECT OF TEMPERATURE AND  $R_G$



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